



Product Overview

NSS35200CF8T1G: Low $V_{CE(sat)}$ Transistor, PNP, 35 V, 7.0 A

For complete documentation, see the data sheet

Product Description

Low $V_{CE(sat)}$ Bipolar Transistors are miniature surface mount devices featuring ultra low saturation voltage $V_{CE(sat)}$ and high current gain capability. These are designed for use in low voltage, high speed switching applications where affordable efficient energy control is important.

Features

- Very Low Saturation
- High Current Switching 2A DC, 7A Peak
- High Current Gain
- High Cut Off Frequency
- Low Profile Package
- Linear Gain (Beta)
- This is a Pb-Free Device

Applications

- DC/DC Converter
- Complimentary Driver
- Supply line Load Switch
- Current Extention & Low Drop Out Regulation
- Battery Charging, Linear & Pulsed

Part Electrical Specifications

Product	Compliance	Status	Polarity	I_C Continuous (A)	$V_{(BR)CEO}$ Min (V)	$V_{CE(sat)}$ Max (V)	h_{FE} Min	h_{FE} Max	f_T Min (MHz)	P_{TM} Max (W)	Package Type
NSS35200CF8T1G	AEC Qualified Pb-free Halide free	Active	PNP	2	35	0.3	100	400	100	2.75	ChipFET-8

For more information please contact your local sales support at www.onsemi.com

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